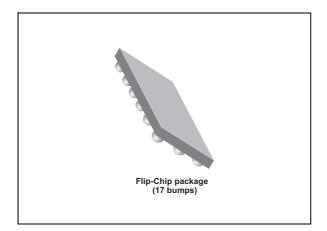


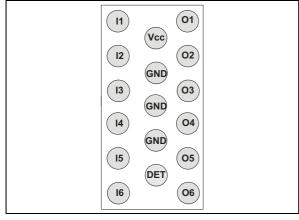
# EMIF06-HSD03F3

Datasheet - production data

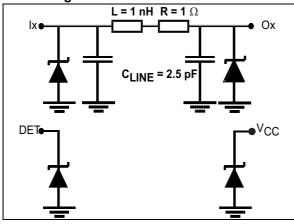
# EMI filter with integrated ESD protection for micro-SD Card™



#### Figure 1. Pin configuration (bump side)







January 2014

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This is information on a product in full production.

#### Features

- Very low line capacitance to compensate long PCB tracks (2.5 pF typ.)
- High efficiency in ESD suppression up to 18 kV (IEC 61000-4-2)
- Very low PCB space consumption:
  - 1.1 x 2.4 mm
- Ultralow leakage current: 20 nA max.
- Very thin package: 0.605 mm
- Smart pinout for easier PCB layout
- High reduction of parasitic elements through integration and wafer level packaging
- Lead-free package

#### Complies with the following standards:

- IEC 61000-4-2 level 4
  - ±15 kV (air discharge)
  - ±8 kV (contact discharge)

## Application

• SD3.0, UHS-1 SDR104 (208 MHz)

## Description

The EMIF06-HSD03F3 chip is a highly integrated device designed to suppress EMI/RFI noise for interface line filtering.

The EMIF06-HSD03F3 Flip-Chip packaging means the package size is equal to the die size. That is why EMIF06-HSD03F3 is a very small device. Additionally, this filter includes ESD protection circuitry, which prevents damage to the protected device when subjected to ESD surges up 18 kV.

# 1 Application diagram

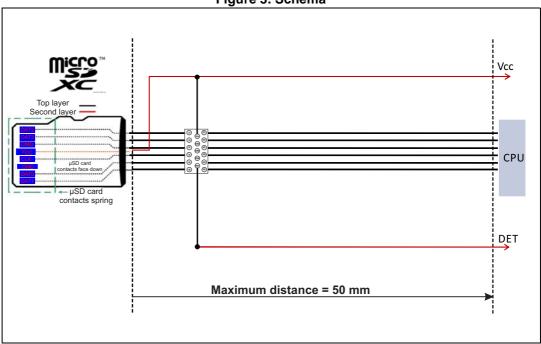


Figure 3. Schema

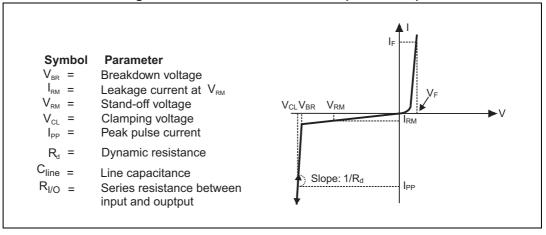


# 2 Characteristics

| Symbol           | Parameter  | Value                | Unit |
|------------------|--|----------------------|------|
| V <sub>PP</sub>  | ESD discharge IEC 61000-4-2, level 4 for Ix pins:<br>Air discharge<br>Contact discharge<br>ESD discharge IEC 61000-4-2, level 1 for Ox pins:<br>Air discharge<br>Contact discharge | 18<br>18<br>10<br>10 | kV   |
| Тj               | Maximum junction temperature   | 125                  | °C   |
| T <sub>OP</sub>  | Operating temperature range  | - 30 to + 85         | °C   |
| T <sub>stg</sub> | Storage temperature range  | - 55 to +150         | °C   |

| Table 1. Absolute maximum | ratings | (T <sub>amb</sub> = | 25 °C) |
|---------------------------|---------|---------------------|--------|
|---------------------------|---------|---------------------|--------|

#### Figure 4. Electrical characteristics (definitions)

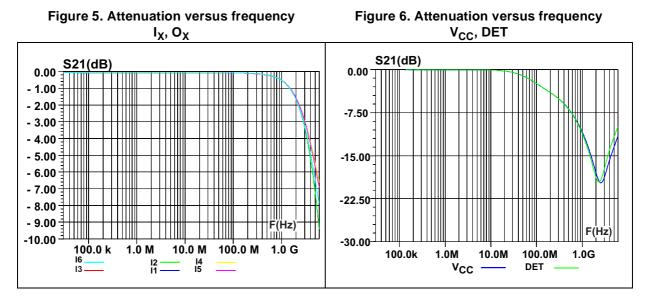




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| Symbol            | Test conditions  |                            |   | Тур. | Max. | Unit  |  |
|-------------------|--|----------------------------|---|------|------|-------|--|
| V <sub>BR</sub>   | Data lines, I <sub>R</sub> = 1 mA  |                            | 5 |      | 9    | V     |  |
| I <sub>RM</sub>   | V <sub>RM</sub> = 3 V per line   |                            |   |      | 20   | nA    |  |
| R <sub>I/O</sub>  |  |                            |   | 1    |      | Ω     |  |
| C <sub>line</sub> | V <sub>line</sub> = 0 V, V <sub>osc</sub> = 30 mV, F = 1 MHz                                       |                            |   | 2.5  | 3    | pF    |  |
| L                 |  |                            |   | 1    |      | nH    |  |
| Dd                | Dynamics registered $t = 100$ so   | IO-GND (positive polarity) |   | 650  |      |       |  |
| Rd                | Dynamics resistance, t <sub>P</sub> = 100 ns   | GND-IO (negative polarity) |   | 320  |      | - m Ω |  |
| V <sub>cc</sub>   |  |                            |   |      |      |       |  |
| V <sub>BR</sub>   | I <sub>R</sub> = 1 mA  |                            | 5 |      | 9    | V     |  |
| I <sub>RM</sub>   | V <sub>RM</sub> = 3 V  |                            |   |      | 20   | nA    |  |
| C <sub>line</sub> | $V_{\text{line}} = 0 \text{ V}, \text{ V}_{\text{osc}} = 30 \text{ mV}, \text{ F} = 1 \text{ MHz}$ |                            |   | 40   |      | pF    |  |
| DET               |  |                            |   |      |      |       |  |
| V <sub>BR</sub>   | I <sub>R</sub> = 1 mA  |                            | 5 |      | 9    | V     |  |
| I <sub>RM</sub>   | V <sub>RM</sub> = 3 V  |                            |   |      | 20   | nA    |  |
| C <sub>line</sub> | $V_{\text{line}} = 0 \text{ V}, V_{\text{osc}} = 30 \text{ mV}, \text{ F} = 1 \text{ MHz}$         |                            |   | 40   |      | pF    |  |





#### Figure 7. ESD response to IEC 61000-4-2 (+8 kV contact discharge)

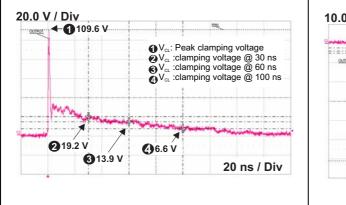
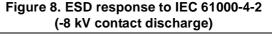
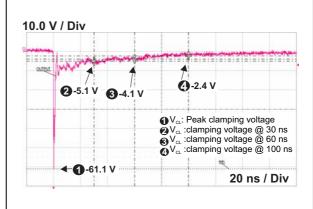


Figure 9. Digital crosstalk I1-O2

Det2

COut





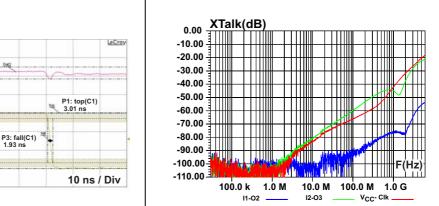


Figure 10. Analog crosstalk versus frequency



1.0 V / Div

P2:rise(C1)

P4: pkpk(C2) 1.28 ns

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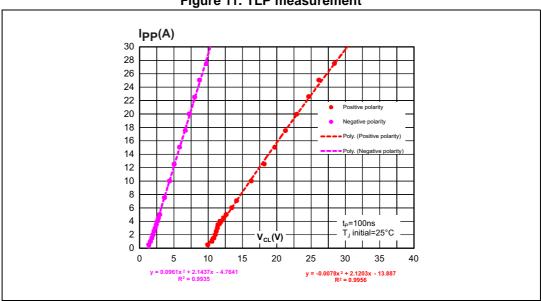


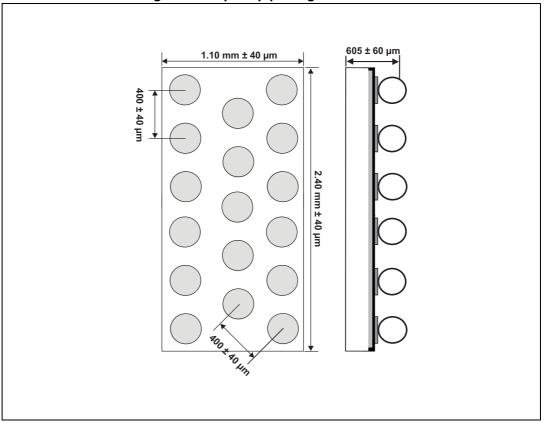
Figure 11. TLP measurement

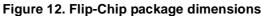


# 3 Package information

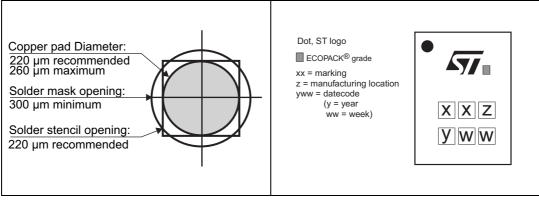
- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK<sup>®</sup> is an ST trademark.

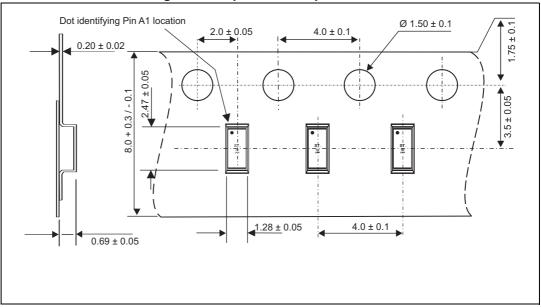














# Note: More information is available in the application notes: AN2348, "IPAD<sup>™</sup> 400 µm Flip Chip: package description and recommendations for use" AN1751, "EMI filters: recommendations and measurements"



# 4 Ordering information

# $\begin{array}{c} \mbox{EMIF} \mbox{06} \mbox{0} \mbox{F3} \mbox{F1} \\ \mbox{EMIF} \mbox{0} \mbox{1} \mbox{F1} \\ \mbox{Muber of lines} \\ \mbox{Application} \\ \mbox{HSD} \mbox{High speed SD card} \\ \mbox{HSD} \mbox{High speed SD card} \\ \mbox{Version} \\ \mbox{Version} \mbox{S1} \\ \mbox{Version} \mbox{S2} \\ \mbox{Fersion} \mbox{S2} \\ \mbox{F1} \mbox{S2} \\ \mbox{F2} \mbox{S2} \\ \mbox{F2} \mbox{S2} \\ \mbox{S2} \mbox{S2} \mbox{S2} \mbox{S2} \\ \mbox{S2} \mbox{S2} \mbox{S2} \mbox{S2} \mbox{S2} \\ \mbox{S2} \mb$

#### Figure 16. Ordering information scheme

#### Table 3. Ordering information

| Order code     | Marking | Package   | Weight | Base qty | Delivery mode      |
|----------------|---------|-----------|--------|----------|--------------------|
| EMIF06-HSD03F3 | KK      | Flip Chip | 3.4 mg | 5000     | Tape and reel (7") |

# 5 Revision history

#### Table 4. Document revision history

| Date        | Revision | Changes   |
|-------------|----------|---|
| 19-Nov-2013 | 1        | Initial release   |
| 10-Jan-2014 | 2        | Reduced size of package image on coverpage, corrected typographic error in Description. |



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